

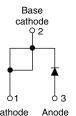
## VS-MBR10...PbF Series, VS-MBR10...-N3 Series

**Vishay Semiconductors** 



# Schottky Rectifier, 10 A





**TO-220AC** 

01	
Cathode	Anoc

PRODUCT SUMMARY						
Package	TO-220AC					
I <sub>F(AV)</sub>	10 A					
V <sub>R</sub>	35 V, 45 V					
V <sub>F</sub> at I <sub>F</sub>	0.57 V					
I <sub>RM</sub> max.	15 mA at 125 °C					
T <sub>J</sub> max.	150 °C					
Diode variation	Single die					
E <sub>AS</sub>	8 mJ					

## **FEATURES**

- 150 °C T<sub>J</sub> operation
- · High frequency operation
- · Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



- RoHS COMPLIANT HALOGEN · Guard ring for enhanced ruggedness and long FREE term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

### DESCRIPTION

This Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	VALUES	UNITS					
I <sub>F(AV)</sub>	Rectangular waveform	10	А					
I <sub>FRM</sub>	T <sub>C</sub> = 135 °C	20	~					
V <sub>RRM</sub>		35/45	V					
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	1060	A					
V <sub>F</sub>	10 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.57	V					
TJ	Range	- 65 to 150	°C					

VOLTAGE RATINGS										
PARAMETER	SYMBOL	VS-MBR1035PbF	VS-MBR1035-N3	VS-MBR1045PbF	VS-MBR1045-N3	UNITS				
Maximum DC reverse voltage	V <sub>R</sub>	35	35	45	45	V				
Maximum working peak reverse voltage	V <sub>RWM</sub>	55	33	45	45	v				

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST	TEST CONDITIONS						
Maximum average forward current	I <sub>F(AV)</sub>	$T_{C}$ = 135 °C, rated $V_{R}$		10	Α				
Peak repetitive forward current	I <sub>FRM</sub>	Rated V <sub>R</sub> , square wave, 20	kHz, T <sub>C</sub> = 135 °C	20	A				
Non-repetitive peak surge current	I <sub>FSM</sub>	5 $\mu s$ sine or 3 $\mu s$ rect. pulse	Following any rated load condition and with rated V <sub>RRM</sub> applied	1060	А				
		Surge applied at rated load conditions halfwave, single phase, 60 Hz		150					
Non-repetitive avalanche energy	E <sub>AS</sub>	$T_J = 25 \ ^{\circ}C, \ I_{AS} = 2 \ A, \ L = 4$	8	mJ					
Repetitive avalanche current	I <sub>AR</sub>	Current decayin Frequency limited by T <sub>J</sub>	2	А					

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ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS				
		20 A	T <sub>J</sub> = 25 °C	0.84	v				
Maximum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	10 A	T <sub>J</sub> = 125 °C	0.57					
		20 A	1j = 125 C	0.72					
Maximum instantaneous reverse current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	Rated DC voltage	0.1	mA				
	IRM \	T <sub>J</sub> = 125 °C	Haleu DC Vollage	15					
Threshold voltage	V <sub>F(TO)</sub>			0.354	V				
Forward slope resistance	r <sub>t</sub>	ij = ij maximum	$T_J = T_J$ maximum						
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal ran	$V_R$ = 5 $V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C						
Typical series inductance	L <sub>S</sub>	Measured from top of term	8.0	nH					
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>	Rated V <sub>R</sub>						

#### Note

 $^{(1)}$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Maximum junction temperature range	TJ		- 65 to 150	о°					
Maximum storage temperature range	T <sub>Stg</sub>		- 65 to 175	C					
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation	2.0	°C/W					
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, smooth and greased (only for TO-220)	0.50	0/11					
Approximate weight			2	g					
Approximate weight			0.07	oz.					
Mounting torgue			6 (5)	kgf ⋅ cm					
maximum			12 (10)	(lbf ⋅ in)					
Marking davias		Case of the TO 220AC	MBR1035						
Marking device		Case style TO-220AC		1045					

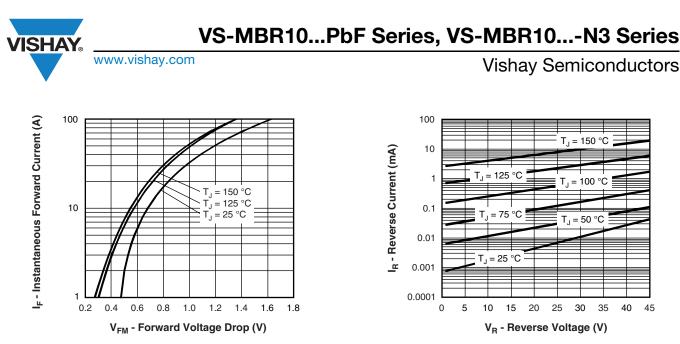
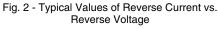


Fig. 1 - Maximum Forward Voltage Drop Characteristics



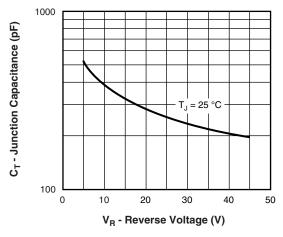
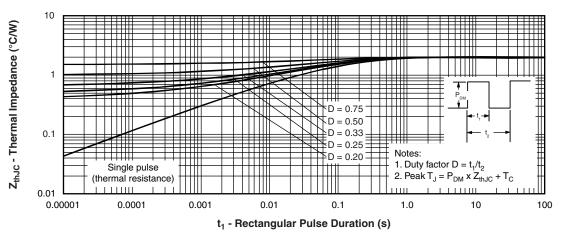


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage





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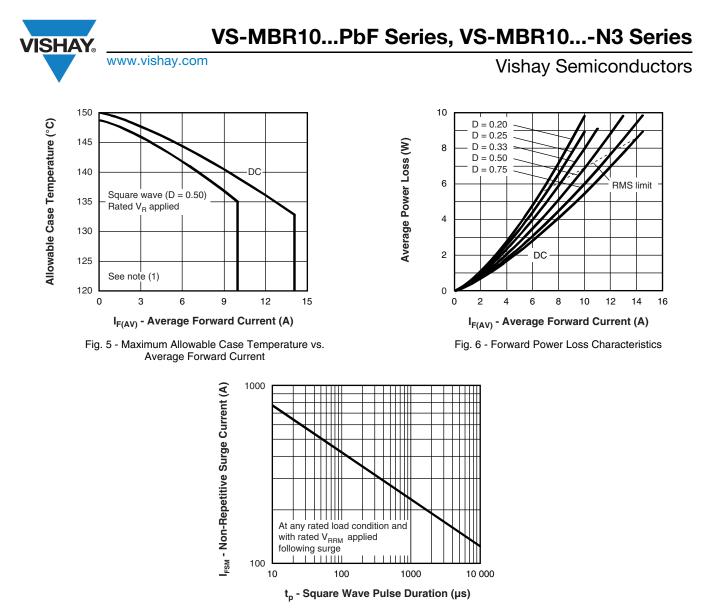


Fig. 7 - Maximum Non-Repetitive Surge Current

#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $\begin{array}{l} \mbox{Pd} = \mbox{Forward power loss} = \mbox{I}_{F(AV)} \times \mbox{V}_{FM} \mbox{ at } (\mbox{I}_{F(AV)}/\mbox{D}) \mbox{ (see fig. 6);} \\ \mbox{Pd}_{REV} = \mbox{Inverse power loss} = \mbox{V}_{R1} \times \mbox{I}_{R} \mbox{ (1 - D); } \mbox{I}_{R} \mbox{ at } \mbox{V}_{R1} = \mbox{Rated V}_{R} \end{array}$ 



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## **ORDERING INFORMATION TABLE**

VS-**Device code MBR** 10 45 4 2 1 (3) Vishay Semiconductors product 1 2

3

4

5

Schottky MBR series

Currrent rating (10 = 10 A)

- 35 = 35 V Voltage ratings 45 = 45 V
- Environmental digit
  - PbF = Lead (Pb)-free and RoHS compliant

PbF

〔5〕

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-MBR1035PbF	50	1000	Antistatic plastic tube						
VS-MBR1035-N3	50	1000	Antistatic plastic tube						
VS-MBR1045PbF	50	1000	Antistatic plastic tube						
VS-MBR1045-N3	50	1000	Antistatic plastic tube						

LINKS TO RELATED DOCUMENTS						
Dimensions www.vishay.com/doc?95221						
Dort moreling information	TO-220AC PbF	www.vishay.com/doc?95224				
Part marking information	TO-220AC -N3	www.vishay.com/doc?95068				
SPICE model		www.vishay.com/doc?95293				



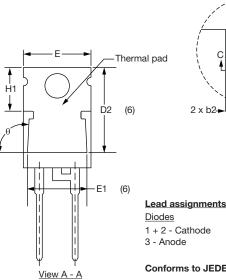
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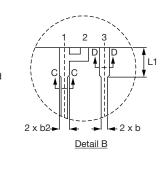
**TO-220AC** 

plane

### **DIMENSIONS** in millimeters and inches









**Diodes** 1 + 2 - Cathode 3 - Anode

Conforms to JEDEC outline TO-220AC

⊕ 0.015 **()** BA()

SYMBOL	MILLIM	IETERS	INC	HES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183		E1	6.86	8.89	0.270	0.350	6
A1	1.14	1.40	0.045	0.055		E2	-	0.76	-	0.030	7
A2	2.56	2.92	0.101	0.115		е	2.41	2.67	0.095	0.105	
b	0.69	1.01	0.027	0.040		e1	4.88	5.28	0.192	0.208	
b1	0.38	0.97	0.015	0.038	4	H1	6.09	6.48	0.240	0.255	6, 7
b2	1.20	1.73	0.047	0.068		L	13.52	14.02	0.532	0.552	
b3	1.14	1.73	0.045	0.068	4	L1	3.32	3.82	0.131	0.150	2
с	0.36	0.61	0.014	0.024		L3	1.78	2.13	0.070	0.084	
c1	0.36	0.56	0.014	0.022	4	L4	0.76	1.27	0.030	0.050	2
D	14.85	15.25	0.585	0.600	3	ØР	3.54	3.73	0.139	0.147	
D1	8.38	9.02	0.330	0.355		Q	2.60	3.00	0.102	0.118	
D2	11.68	12.88	0.460	0.507	6	θ	90° t	o 93°	90° t	o 93°	
E	10.11	10.51	0.398	0.414	3, 6						

Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

- <sup>(2)</sup> Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- <sup>(4)</sup> Dimension b1, b3 and c1 apply to base metal only
- <sup>(5)</sup> Controlling dimension: inches
- <sup>(6)</sup> Thermal pad contour optional within dimensions E, H1, D2 and E1
- <sup>(7)</sup> Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- <sup>(8)</sup> Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline

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